

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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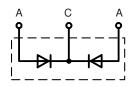




HiPerFRED™ Epitaxial Diode with common cathode and soft recovery

 $I_{FAV} = 2x8 A$ $V_{RRM} = 200 V$ $t_{rr} = 25 ns$

V _{RSM}	V _{RRM} V	Туре
200	200	DSEC 16-02A



TO-220 AB



A = Anode, C = Cathode, TAB = Cathode

Symbol	Conditions	Maximum	imum Ratings	
I _{FRMS}		35	Α	
I _{FAVM}	$T_C = 150$ °C; rectangular, $d = 0.5$	8	Α	
I _{FRM}	$t_{P} < 10~\mu s;$ rep. rating, pulse width limited by T_{VJM}	tbd	Α	
I _{FSM}	$T_{VJ} = 45^{\circ}C; t_p = 10 \text{ ms } (50 \text{ Hz}), \text{ sine}$	80	A	
E _{AS}	T _{vJ} = 25°C; non-repetitive	0.5	mJ	
	$I_{AS} = 2 A; L = 180 \mu H$.	
I _{AR}	$V_A = 1.5 \cdot V_R \text{ typ.}$; f = 10 kHz; repetitive	0.2	А	
T_{VJ}	-5.	5+175	°C	
T_{VJM}		175	°C	
T_{stg}	-5.	5+150	°C	
P _{tot}	T _C = 25°C	60	W	
M _d	mounting torque	0.40.6	Nm	
Weight	typical	2	g	

Symbol	Conditions	Characteristic Values		
		typ.	max.	
I _R ①	$T_{VJ} = 25$ °C $V_R = V_{RRM}$ $T_{VJ} = 150$ °C $V_R = V_{RRM}$		50 0.2	μA mA
V _F ②	$I_F = 8 \text{ A};$ $T_{VJ} = 150^{\circ}\text{C}$ $T_{VJ} = 25^{\circ}\text{C}$		0.94 1.30	V
R _{thJC} R _{thCH}		0.5	2.5	K/W K/W
t _{rr}	$I_F = 1 \text{ A}; -di/dt = 50 \text{ A}/\mu\text{s};$ $V_R = 30 \text{ V}; T_{VJ} = 25^{\circ}\text{C}$	25		ns
I _{RM}	V_{R} = 100 V; I_{F} = 10 A; -di _F /dt = 100 A/ μ s T_{VJ} = 100°C		4.1	А

Features

- International standard package
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low I_{RM}-values
- · Soft recovery behaviour
- Epoxy meets UL 94V-0

Applications

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating
- Uninterruptible power supplies (UPS)
- · Ultrasonic cleaners and welders

Advantages

- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low $I_{\mbox{\tiny RM}}$ reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Dimensions see Outlines.pdf

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0% ② Pulse Width = $300 \mu s$, Duty Cycle < 2.0%

Data according to IEC 60747 and per diode unless otherwise specified

IXYS reserves the right to change limits, test conditions and dimensions.

Recommended replacement: DPG20C200PB

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